

SPICE Device Model SUM110N06-04L Vishay Siliconix

N-Channel 60-V (D-S) 200°C MOSFET

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

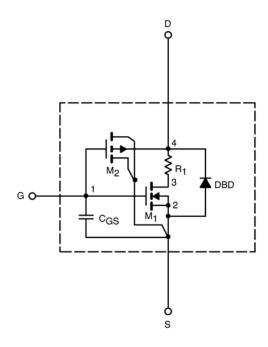
- Apply for both Linear and Switching Application
- Accurate over the –55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125° C temperature ranges under the pulsed 0 to 10V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Conditions	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2.1		V
On-State Drain Current ^a	I _{D(on)}	$V_{DS} > 5 \text{ V}, V_{GS} = 10 \text{ V}$	1751		Α
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = 10 V, I _D = 30 A	0.0026	0.0028	Ω
		V _{GS} = 4.5 V, I _D = 20 A	0.0037	0.0040	
		V _{GS} = 10 V, I _D = 30 A, T _J = 125°C	0.0044		
		V _{GS} = 10 V, I _D = 30 A, T _J = 200°C	0.0058		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 30 A	132		S
Forward Voltage ^a	V_{SD}	I _S = 110 A, V _{GS} = 0 V	0.93	1.1	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 25 V, f = 1 MHz	7380	7500	pf
Output Capacitance	Coss		1079	1050	
Reverse Transfer Capacitance	C _{rss}		616	700	
Total Gate Charge ^c	Q_g	V_{DS} = 30 V, V_{GS} = 10 V, I_{D} = 110 A	149	150	nc
Gate-Source Charge ^c	Q_{gs}		25	25	
Gate-Drain Charge ^c	Q_{gd}		45	45	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD}=30~V,~R_L=0.40~\Omega$ $I_D\cong 110~A,~V_{GEN}=10~V,~R_G=2.5~\Omega$ $I_F=110~A,~di/dt=100~A/\mu s$	67	20	ns
Rise Time ^c	t _r		84	135	
Turn-Off Delay Time ^c	$t_{d(off)}$		100	80	
Fall Time ^c	t _f		127	150	
Reverse Recovery Time	t _{rr}		55	75	

Notes

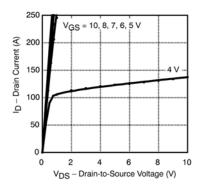
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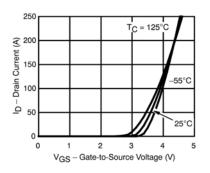
a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2%. b. Guaranteed by design, not subject to production testing. c. Independent of operating temperature.

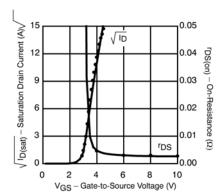


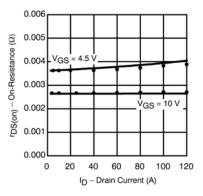
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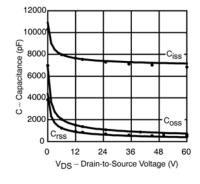
COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

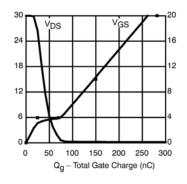












Note: Dots and squares represent measured data.



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